









	<h2>SI1300BDL-T1-E3</h2>
	<p>codice articolo del costruttore: SI1300BDL-T1-E3</p> <hr/> <p>Costruttore / Marca: Vishay / Siliconix</p> <hr/> <p>Parte della descrizione: MOSFET N-CH 20V 400MA SOT323-3</p> <hr/> <p>Schede tecniche:  SI1300BDL-T1-E3.pdf</p> <hr/> <p>Stato di RoHs: Senza piombo / RoHS conforme</p> <hr/> <p>Condizione di scorta: New original, 9285 pcs Stock Available.</p> <hr/> <p>Nave da: Hong Kong</p> <hr/> <p>Modo di spedizione: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

specificazioni

Numero di parte	SI1300BDL-T1-E3
fabbricante	Vishay / Siliconix
Descrizione	MOSFET N-CH 20V 400MA SOT323-3
Categoria	Prodotti a semiconduttore discreti > Transistor-FET ,
Stato parte	9285 pcs Stock
Serie	TrenchFET®
Tecnologia	MOSFET (Metal Oxide)
temperatura di esercizio	-55°C ~ 150°C (TJ)
Tipo montaggio	Surface Mount
Contenitore / involucro	SC-70, SOT-323
Contenitore dispositivo fornitore	SC-70-3
Dissipazione di potenza (max)	190mW (Ta), 200mW (Tc)
Tipo FET	N-Channel
Caratteristica FET	-
Tensione drain-source (Vdss)	20V
Corrente - Drain continuo (Id) @ 25 ° C	400mA (Tc)
Rds On (max) a Id, Vgs	850 mOhm @ 250mA, 4.5V
Vgs (th) (max) a Id	1V @ 250µA
Carica Gate (Qg) (Max) @ Vgs	0.84nC @ 4.5V
Capacità di ingresso (Ciss) (Max) @ Vds	35pF @ 10V
imballaggio	Tape & Reel (TR)












































SI1300BDL-T1-E3 è nuovo originale in magazzino, ricerca datasheet SI1300BDL-T1-E3, PDF, inventario Y-IC.com online, ordine SI1300BDL-T1-E3 Vishay / Siliconix con garanzia e garanzia. RFQ SI1300BDL-T1-E3: Info@Y-IC.com

Potresti essere anche interessato:

 <p>SI117XG2-KIT Energy Micro (Silicon Labs) THE SI117XG2-KIT EVALUATION OF S</p>	 <p>SI117XE2-KIT Energy Micro (Silicon Labs) THE SI117XE2-KIT EVALUATES THE S</p>	 <p>SI13-0D BESTA BESTA QFP</p>	 <p>SI1300DL-T1 SILICON SI1300DL-T1 SILICON</p>
 <p>SI1300BDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 400MA SC- 70-3</p>	 <p>SI1300DL VISHAY SI1300DL VISHAY</p>	 <p>SI12301DS-T1 VISHAY VISHAY SOT-23</p>	 <p>SI123DL SI SI DIP</p>

Hot Parts

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 SI1069X-T1-E3	 SI1069X-T1-GE3	 SI1069X-T1-GE3	D SI1070X-T1-E3	 SI1070X-T1-E3
 SI1070X-T1-GE3	 SI1070X-T1-GE3	D SI1071X-T1-GE3	 SI1071X-T1-GE3	 SI1072X-T1-E3
 SI1072X-T1-E3	 SI1072X-T1-GE3	 SI1072X-T1-GE3	 SI1073X-T1-GE3	 SI1073X-T1-GE3
D SI1120-A-GMR	 SI1132-A10-GMR	 SI1133-AA00-GMR	 SI113DP-T1-GE3	 SI1141-A10-GMR
 SI1142-A11-GMR	 SI1143-A11-GMR	 SI1143-M01-GMR	 SI1144-AAGX-GMR	 SI1300BDL-T1-E3
 SI1300BDL-T1-GE3	 SI1300BDL-T1-GE3	D SI1300DL	 SI1300DL-T1	 SI1300DL-T1-GE3
 SI1301DL	D SI1301DL-T1	 SI1301DL-T1-E3	 SI1301DL-T1-GE3	 SI1301DL-T1/LGW
 SI1302DL	 SI1302DL-T1-E3	 SI1302DL-T1-E3	 SI1302DL-T1-GE3	 SI1302DL-T1-GE3
 SI1303DL	 SI1303DL-T1	 SI1303DL-T1-E3	D SI1303DL-T1-E3	 SI1303DL-T1-GE3
 SI1303DL-T1-GE3	 SI1303DL-TL-E3	 SI1303EDL-T1-GE3	 SI1304BDL-T1-GE3	 SI1304BDL-T1-GE3

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